

High Efficiency Fast Response, 2A, 22V Input Synchronous Step Down Regulator

General Description

HM2271 develops high efficiency synchronous step-down DC-DC converter capable of delivering 2A load current. HM2271 operates over a wide input voltage range from 4.5V to 22V and integrates main switch and synchronous switch with very low $R_{DS(ON)}$ to minimize the conduction loss.

HM2271 adopts the instant PWM architecture to achieve fast transient responses for high step down applications and high efficiency at light loads. In addition, it operates under heavy load conditions to minimize the size of inductor and capacitor.

Features

- Low $R_{DS(ON)}$ for internal switches (top/bottom): 145/135 mΩ
- 4.5-22V input voltage range
- 2A load current capability
- Instant PWM architecture to achieve fast transient responses
- Internal softstart limits the inrush current
- 2% 0.6V reference
- RoHS Compliant and Halogen Free
- Compact package: SOT23-6

Package

SOT23-6

Applications

- Set Top Box
- Portable TV
- Access Point Router
- DSL Modem
- LCD TV

Typical Applications

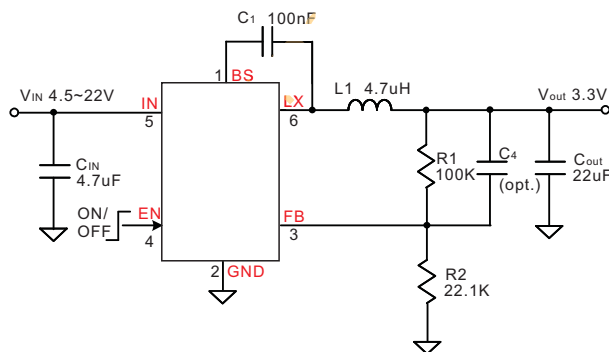


Figure1.Schematic Diagram

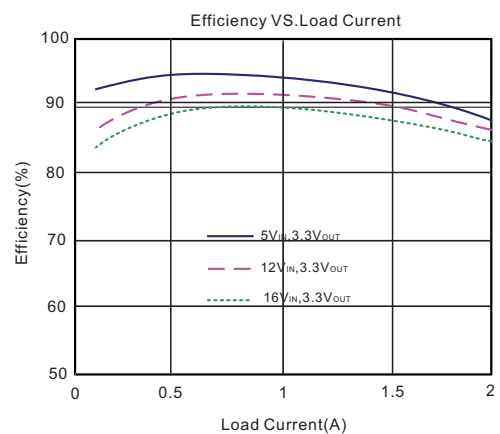
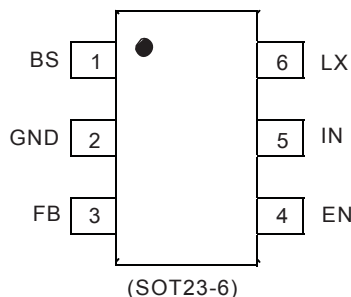


Figure2.Efficiency Figure

PIN Configuration and Functions



NO	NAME	I/O	DESCRIPTION
1	BS	I	Boot-Strap Pin. Supply high side gate driver. Decouple this pin to LX pin with 0.1 uF ceramic cap.
2	GND	P	Ground pin
3	FB	I	Output Feedback Pin. Connect this pin to the center point of the output resistor divider (as shown in Figure 1) to program the output voltage: $V_{out}=0.6 \cdot (1+R1/R2)$
4	EN	I	Enable control. Pull high to turn on. Do not float.
5	IN	I	Input pin. Decouple this pin to GND pin with at least 1uF ceramic cap
6	LX	O	Inductor pin. Connect this pin to the switching node of inductor

Absolute Maximum Ratings (Note 1)

Supply Input Voltage	-----23V
LX, EN Voltage	-----IN + 0.3V
FB, BS-LX Voltage	-----4V
Power Dissipation, PD@ TA= 25°C SOT23-6	-----0.6W

Package Thermal Resistance (Note 2)

θ_{JA}	-----170°C/W
θ_{JC}	-----130°C/W
Junction Temperature Range	-----125°C
Lead Temperature (Soldering, 10 sec.)	-----260°C
Storage Temperature Range	----- -65°C to 150°C

Package Thermal Resistance (Note 3)

Supply Input Voltage	-----4.5V to 22V
Junction Temperature Range	----- -40°C to 125°C
Ambient Temperature Range	----- -40°C to 85°C

Electrical Characteristics

($V_{IN}=12V$, $V_{OUT}=1.2V$, $L=25\mu H$, $C_{OUT}=10\mu F$, $T_A=25^\circ C$, $I_{OUT}=1A$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{IN}		4.5		22	V
Quiescent Current	I_Q	$I_{OUT}=0$, $V_{FB}=V_{REF}\times 105\%$		0.1		μA
Shutdown Current	I_{SHDN}	$EN=0$		5	10	μA
Feedback Reference Voltage	V_{REF}		0.588	0.6	0.612	V
FB Input Current	I_{FB}	$V_{FB}=V_{IN}$	-50		50	nA
Top FET RON	$R_{DS(ON)1}$			0.145		Ω
Bottom FET RON	$R_{DS(ON)2}$			0.135		Ω
TOP FET Peak Current Limit	$I_{LIM, TOP}$				3.6	A
Bottom FET Valley Current Limit	$I_{LIM, BOTTOM}$		2			A
EN Rising Threshold	V_{ENH}		1.5			V
EN Falling Threshold	V_{ENL}				0.4	V
Input UVLO Threshold	V_{UVLO}				4.5	V
Switching Frequency	F_{SW}			500		kHz
Min ON Time				50		ns
Min Off Time				100		ns
Soft-start Time	t_{SS}			800		us
Thermal Shutdown Temperature	T_{SD}			150		$^\circ C$
Thermal Shutdown Hysteresis	T_{HYS}			15		$^\circ C$

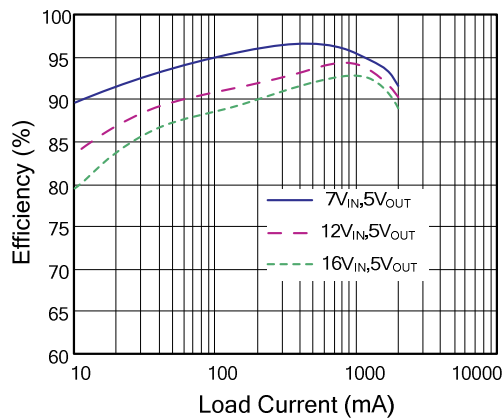
Note 1: Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at $T_A=25^\circ C$ on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. Pin 2 of SOT-23-6 packages is the case position for θ_{JC} measurement.

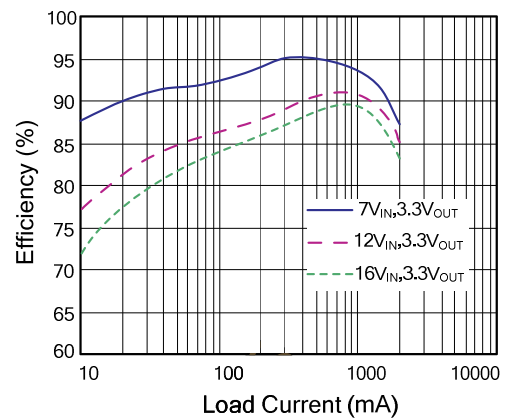
Note 3: The device is not guaranteed to function outside its operating conditions.

TYPICAL CHARACTERISTICS

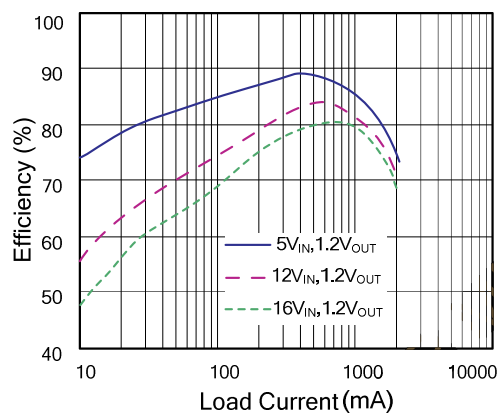
Efficiency vs. Load Current



Efficiency vs. Load Current

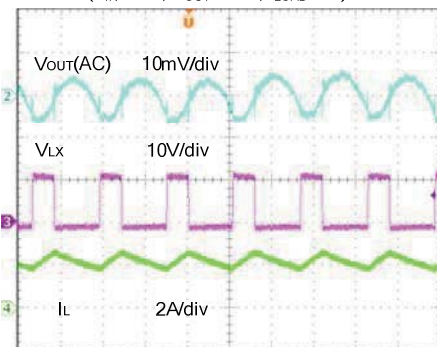


Efficiency vs. Load Current



Output Ripple

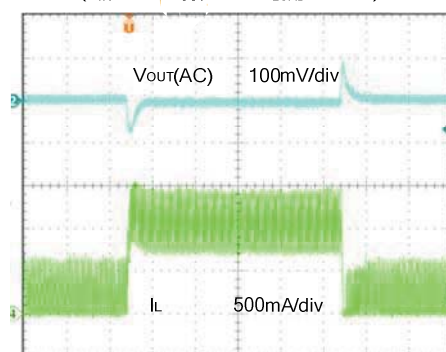
(V_{IN}=12V, V_{OUT}=3.3V, I_{LOAD}=2A)



Time (1μs/div)

Load Transient

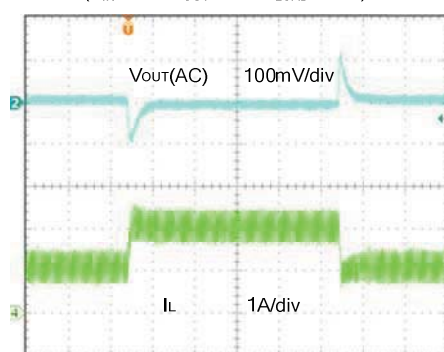
(V_{IN}=12V, V_{OUT}=3.3V, I_{LOAD}=0.2-1A)



Time 40μs/div

Load Transient

(V_{IN}=12V, V_{OUT}=3.3V, I_{LOAD}=1-2A)

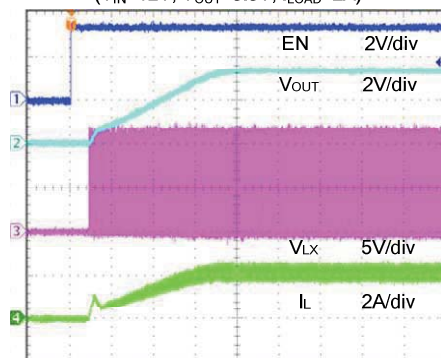


Time 40μs/div

TYPICAL CHARACTERISTICS

Startup

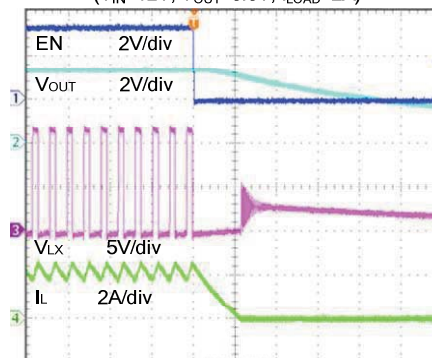
($V_{IN}=12V$, $V_{OUT}=3.3V$, $I_{LOAD}=2A$)



Time (100us/div)

Shutdown

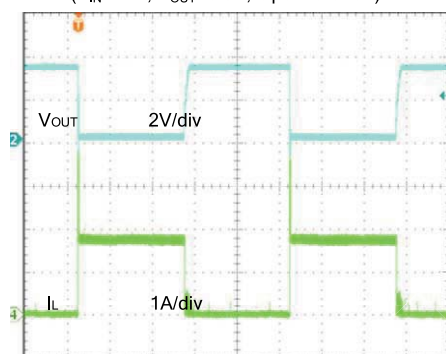
($V_{IN}=12V$, $V_{OUT}=3.3V$, $I_{LOAD}=2A$)



Time (4us/div)

Short Circuit Protection

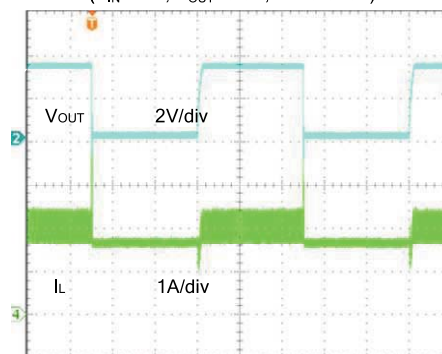
($V_{IN}=12V$, $V_{OUT}=3.3V$, Open to Short)



Time (2ms/div)

Short Circuit Protection

($V_{IN}=12V$, $V_{OUT}=3.3V$, 2A to Short)



Time (2ms/div)

Operation

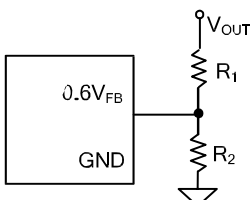
HM2271 is a synchronous buck regulator IC that integrates the PWM control, top and bottom switches on the same die to minimize the switching transition loss and conduction loss. With ultra low $R_{ds(on)}$ power switches and proprietary PWM control, this regulator IC can achieve the highest efficiency and the highest switch frequency simultaneously to minimize the external inductor and capacitor size, and thus achieving the minimum solution footprint. HM2271 provides protection functions such as cycle by cycle current limiting and thermal shutdown protection. HM2271 will sense the output voltage conditions for the fault protection.

Applications Information

Because of the high integration in the HM2271 IC, the application circuit based on this regulator IC is rather simple. Only input capacitor C_{in} , output capacitor C_{out} , output inductor L and feedback resistors (R_1 and R_2) need to be selected for the targeted applications specifications.

Feedback resistor dividers R_1 and R_2 :

Choose R_1 and R_2 to program the proper output voltage. To minimize the power consumption under light loads, it is desirable to choose large resistance values for both R_1 and R_2 . A value of between 10k Ω and 1M Ω is highly recommended for both resistors. If V_{out} is 3.3V, $R_1=100k$ is chosen, then using following equation, R_2 can be calculated to be 22.1k.

$$R_2 = \frac{0.6V}{V_{OUT} - 0.6V} R_1$$


Input capacitor C_{in} :

The ripple current through input capacitor is calculated as:

$$I_{CIN_RMS} = I_{OUT} \cdot \sqrt{D(1-D)}$$

To minimize the potential noise problem, place a typical X5R or better grade ceramic capacitor really close to the IN and GND pins. Care should be taken to minimize the loop area formed by C_{in} and IN/GND pins. In this case, a 4.7 μ F low ESR ceramic capacitor is recommended.

Output capacitor C_{out} :

The output capacitor is selected to handle the output ripple noise requirements. Both steady state ripple and transient requirements must be taken into consideration when selecting this capacitor. For the best performance, it is recommended to use X5R or better grade ceramic capacitor greater than 22 μ F capacitance.

Output inductor L :

There are several considerations in choosing this inductor. (1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple current to be about 40% of the maximum output current. The inductance is calculated as:

$$L = \frac{V_{OUT}(1 - V_{OUT}/V_{IN,MAX})}{F_{SW} \times I_{OUT,MAX} \times 40\%}$$

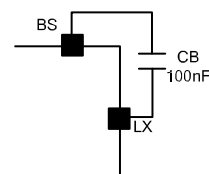
where F_{sw} is the switching frequency and $I_{out,MAX}$ is the maximum load current. The HM2271 regulator IC is quite tolerant of different ripple current amplitude. Consequently, the final choice of inductance can be slightly the calculation value without significantly impacting the performance. (2) The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions.

$$I_{SAT, MIN} > I_{OUT, MAX} + \frac{V_{OUT}(1 - V_{OUT}/V_{IN,MAX})}{2 \cdot F_{SW} \cdot L}$$

(3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. It is desirable to choose an inductor with $DCR < 50m\Omega$ to achieve a good overall efficiency.

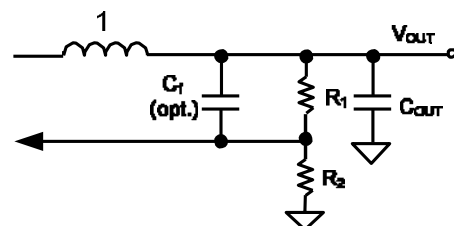
External Bootstrap Cap

This capacitor provides the gate driver voltage for internal high side MOSFET. A 100nF low BSR ceramic capacitor connected between BS pin and LX pin is recommended.



Load Transient Considerations:

The HM2271 regulator IC integrates the compensation components to achieve good stability and fast transient responses. In some applications, adding a 22pF ceramic cap in parallel with R_1 may further speed up the load transient responses and is thus recommended for applications with large load transient step requirements.

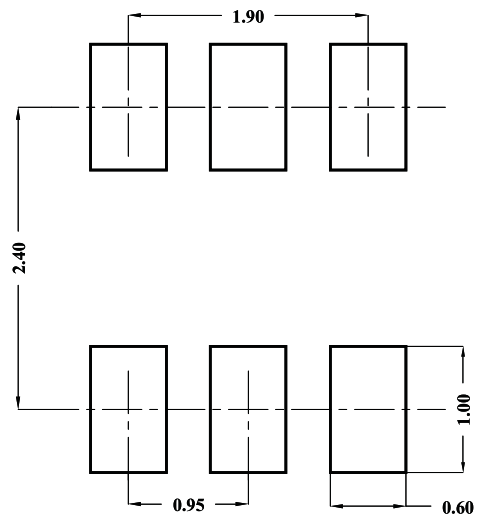


Layout Design:

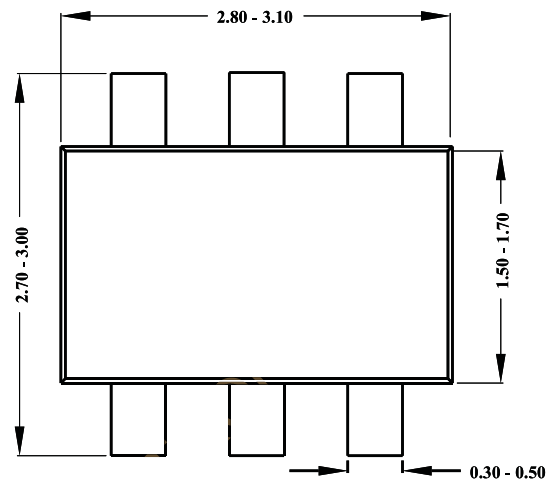
The layout design of HM2271 regulator is relatively simple. For the best efficiency and minimum noise problem, we should place the following components close to the IC: C_{IN}, L, R1 and R2.

- 1) It is desirable to maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. If the board space allowed, a ground plane is highly desirable.
- 2) C_{IN} must be close to Pins IN and GND. The loop area formed by C_{IN} and GND must be minimized.
- 3) The PCB copper area associated with LX pin must be minimized to avoid the potential noise problem.
- 4) The components R1 and R2, and the trace connecting to the FB pin must NOT be adjacent to the LX net on the PCB layout to avoid the noise problem.
- 5) If the system chip interfacing with the EN pin has a high impedance state at shutdown mode and the IN pin is connected directly to a power source such as a Li-Ion battery, it is desirable to add a pull down 1Mohm resistor between the EN and GND pins to prevent the noise from falsely turning on the regulator at shutdown mode.

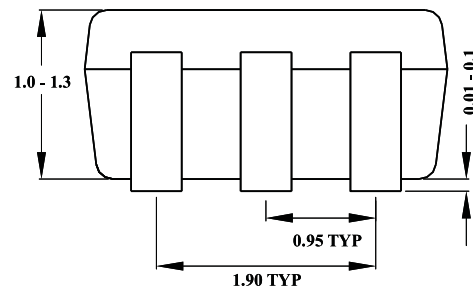
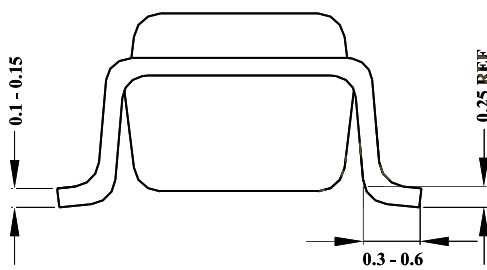
SOT23-6L Package Outline & PCB layout



Recommended Pad Layout



Top View

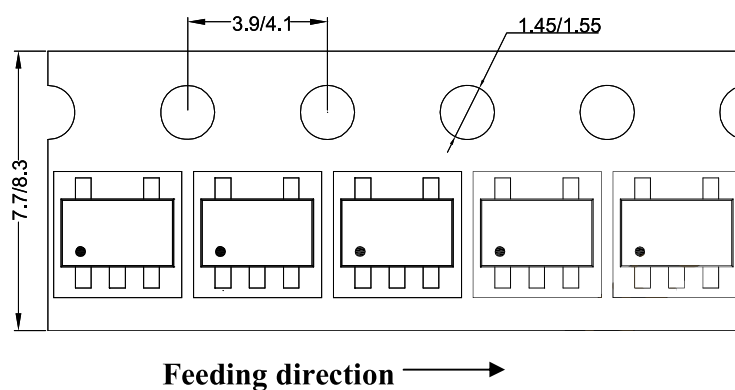


Notes: All dimension in MM
 All dimension don't not include mold flash & metal burr

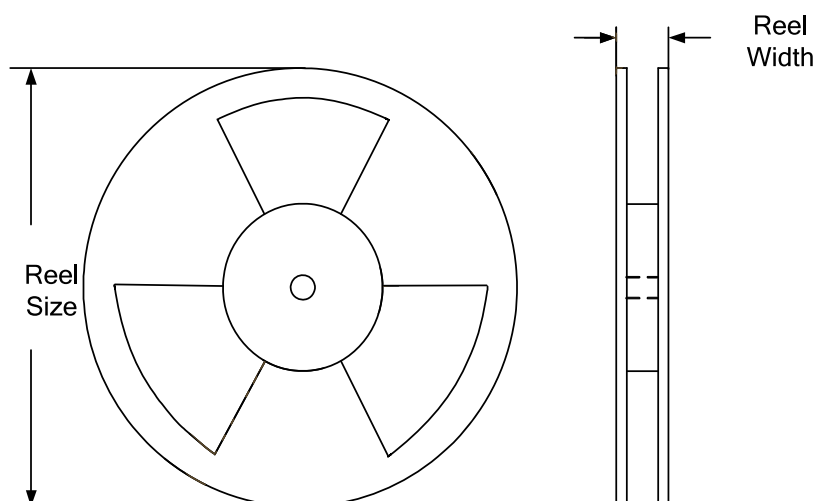
Taping & Reel Specification

1. Taping orientation

SOT23-6



2. Carrier Tape & Reel specification for packages



Package types	Tape width (mm)	Pocket pitch(mm)	Reel size (Inch)	Reel width(mm)	Trailer length(mm)	Leader length (mm)	Qty per reel
SOT23-6	8	4	7"	8.4	280	160	3000



MOS 电路操作注意事项：

静电在很多地方都会产生，采取下面的预防措施，可以有效防止 MOS 电路由于受静电放电影响而引起的损坏：

- 操作人员要通过防静电腕带接地。
- 设备外壳必须接地。
- 装配过程中使用的工具必须接地。
- 必须采用导体包装或抗静电材料包装或运输。

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